NSN 5961-00-192-0045

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-192-0045 **Inclosure Material:** Plastic **Overall Length:** 0.260 inches **Overall Height:** 0.050 inches **Overall Width:** 0.150 inches **Component Name And Quantity:** 22 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 60.0 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current absolute all semiconductor device diode **Power Rating Per Characteristic:** 450.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: